- 1. Consider two infinite, plane parallel, perfectly conducting plates at z=0 and $z=z_o>0$, which hold equal and opposite surface charge densities and are kept at potentials V=0 and $V=V_p>0$, respectively. The region between the plates is filled with two slabs of perfect dielectric materials having permittivities ϵ_1 for 0 < z < d (region 1) and ϵ_2 for $d < z < z_o$ (region 2).
 - a) Find the general solution for the electric potentials, V = V(z), (in terms of V_p , d, z_0 , ϵ_1 , and ϵ_2) in the two regions by solving Laplace's equation piecewise and enforcing the continuity of V(z) at z = d. Hint: you will also need to use the fact that there is no surface charge accumulation at a boundary between two perfect dielectrics.
 - b) Given that $z_o = 4d = 2$ m, $\epsilon_1 = 3\epsilon_o$, $\epsilon_2 = \epsilon_o$, and $\mathbf{E}(0 < z < d) = -5\hat{z}$ V/m, what is the electrostatic potential V_p on the conductor plate at $z = z_0$?
 - c) Given the parameters in part (b) above, what is the surface charge density ρ_s on the plate at $z=z_o$?
- 2. Consider two conducting plates positioned on z=0 and z=3 m surfaces. The plates are grounded and both have zero potential. In between the plates, on z=1 m surface, there is a uniform and static surface charge of $6 \, \text{C/m}^2$. The permittivity of the region z<1 m is ϵ_o , whereas it is $2\epsilon_o$ in the region z>1 m. Determine the surface charge densities at z=0 and z=3 m.

Hint: Let V_o denote the electrostatic potential at z = 1. Express the electric and displacement fields above and below z = 1 in terms of V_o and use boundary condition equations on z = 0, 1, and 3 m surfaces to relate V_o to pertinent surface charge densities.

3. The region between two infinite, plane parallel, perfectly conducting plates at z=0 and $z=z_0$ m is filled with two slabs of perfect dielectric materials having constant electric permittivities ϵ_1 for 0 < z < d m (region 1) and ϵ_2 for $d < z < z_0$ (region 2), where d=4 m. The bottom plate is held at constant potential V_0 , while the top plate is grounded, such that $V(z_0)=0$. The electrostatic field between the plates is known to be

$$\mathbf{E}(z) = \begin{cases} \frac{4\epsilon_2}{\epsilon_1 + 8\epsilon_2} \hat{z} \frac{\mathbf{V}}{\mathbf{m}}, & 0 < z < d \\ \frac{4\epsilon_1}{\epsilon_1 + 8\epsilon_2} \hat{z} \frac{\mathbf{V}}{\mathbf{m}}, & d < z < z_0 \end{cases}$$

- a) Verify that the above field satisfies Maxwell's boundary condition regarding \mathbf{D} at the boundary between the two dielectric slabs.
- b) Write the expression for the electrostatic potential V(z) throughout both regions (i.e., for $0 < z < z_0$ m) in terms of ϵ_1 , ϵ_2 , z_0 , V_0 , and d.
- c) Determine ϵ_1 if $\epsilon_2=2\epsilon_0$ and the surface charge density on the bottom plate (at z=0 m) is $\rho_s=4\epsilon_0$ C/m².
- d) What is the thickness of region 2 in meters if $V_0 = 3$ V?
- e) Does V(z) determined in part (b) satisfy Laplace's equation in the region $0 < z < z_0$ m? Explain your answer.
- f) What would be the capacitance C of the structure described above if the parallel plates at z=0 and $z=z_0$ m were constrained to have finite areas $A=W^2$ (where $W\gg 1$ m) facing one another? In this calculation ignore the fringing fields, and express C as a function of ϵ_1 , ϵ_2 , d, z_0 and A.

- 4. Copper is a highly conducting metal with a **conductivity** of $\sigma = 5.8 \times 10^7$ S/m and a free-electron density of $N_e = 8.45 \times 10^{28}$ m⁻³.
 - a) Determine the resistance R of a copper wire of radius r = 1.4 mm and length d = 180 m using

$$R = \frac{1}{G} = \frac{d}{A\sigma}$$

from Lecture 10. A denotes the cross-sectional are of the wire.

- b) What would be the magnitude of electric field **E** within the wire of part (a) if the wire were conducting a 1 A current? You may assume a uniform current distribution across the wire cross section.
- c) With the electric field determined from part (b), what would be the mean speed $|\mathbf{v}|$ of an electron in the wire? **Hint:** first deduce the current density $\mathbf{J} = \sigma \mathbf{E}$ in the wire, and then use the fact that $\mathbf{J} = N_e q \mathbf{v}$ in the copper wire, with $q = -e = -1.6 \times 10^{-19}$ C denoting the charge of an electron.
- d) How long would it take the electron in part (c) to drift from one end of the wire to the other? **Hint:** you may be surprised by the result of your calculation.
- 5. Consider a pair of metallic spherical shells of radii a and b > a with their centers coinciding with the origin of the reference coordinate system. The medium between the shells has permittivity $\epsilon = 2\epsilon_o$ and conductivity $\sigma = 2 \times 10^{-6}$ S/m.
 - a) Use the integral form of Gauss's law to relate the static field between the shells to charge Q residing on the (outer) surface of the inner shell with radius a and integrating the field from radius a to b obtain the relation Q = CV where V is the potential drop from the inner to outer shell and

$$C = 4\pi\epsilon \frac{ab}{b-a}$$

- b) Taking the limit of capacitance C as $b \to \infty$, obtain the capacitance (in pF) of a metallic shell of radius a=1 m embedded in an infinite region of permittivity $\epsilon=2\epsilon_o$ and conductivity $\sigma=2\times 10^{-6}$ S/m.
- c) What is the conductance (in μ S) of the metallic shell configuration described in (b). **Hint:** make use of $G = \frac{\sigma}{\epsilon}C$ relation from class notes.
- d) Develop an RC equivalent circuit to represent the physical system described above. Use this equivalent circuit to derive a differential equation that governs the temporal variation of the charge on the spherical shell. **Hint:** in this circuit the lossy capacitor (see Lect 10, page 4) conducts no external current (since external circui is an effective open in this case there is no path for the return current).
- e) Assume Q(t) = 1 C on the shell with radius a at t = 0. The radial electric field produced by Q(t) will drive a radial current to discharge the shell. Obtain an expression for Q(t) in t > 0 that describes the discarge of the metallic shell by solving the differential equation obtained in (d).